3GPP TSG-RAN WG4 Meeting # 116 R4-2511766

Bengaluru , IN, August 25 – 29, 2025

Agenda item: 7.3.3

Source: Apple, Samsung

Title: TP to TR38.768 on low NR band aggregation via switching

WI/SI: NR\_LBCA\_Sw-Core

Release: Rel-19

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# 1 Introduction

In the previous RAN4 meeting (Meeting #115, Malta, 19th – 23rd May, 2025), several aspects of the low NR band aggregation via switching feature were debated. As highlighted in the meeting WF [1], agreements were made on the time masks, switching period locations, as well as the addition of 70μs to the list of switching period values, resulting in a set of 3 values (35μs, 70μs, and 140μs) as possible values for the UE switching period capability when the UE supports the low NR band aggregation via switching feature. The TR38.768 [2] was updated to include the requirements for the time masks and switching period locations. However, the new value of the switching period (70μs) was not added in the TR.

This contribution provides the following text proposals to TR38.768:

- Change 1: Include 70μs switching period value in all the clauses where the switching period values are captured.

- Change 2: Add the applicability of the inter-band carrier aggregation aspects for a UE which supports the low NR band carrier aggregation via switching

- Change 3: The configuration aspects related to low NR band carrier aggregation via switching

- Change 4: Impact on MSD requirements

- Change 5: Impact on ΔRIB,c and ΔTIB,c requirements

- Change 6: Aspects related to the RMCs

# 2 References

[1] R4-2508118, “WF on UE RF requirements for LB CA via switching,” by Apple, 3GPP RAN4 #115, Malta, 19th – 23rd May, 2025

[2] R4-2508119, “TR 38.768-004” by Apple, 3GPP RAN4 #115, Malta, 19th – 23rd May, 2025

[3] R4-2505439, “UE RF requirements for LB CA via switching,” Apple, 3GPP RAN4 #115, May 2025

# 3 Text Proposal

<< begin change 1 >>

## 5.1 Switching periods

To accommodate different UE implementations, RAN4 has reached the agreement in RAN4#114 on the applicable switching periods of 35μs, 70μs, and 140μs for switching between Case 1 and Case 2 as an optional UE capability.

## 5.2 Switching period location

### 5.2.1 General

 For what follows we consider switching between an FDD and SDL band for the CA-n5A-29A configuration in Table 4-1 but without loss of generality: one UL is configured in a paired band with the DL Scell configured in either a DL band of another paired band or in an SDL band.

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The timing reference for the switching pattern and switching gap at the UE is the DL timing of the Pcell (in the FDD band). The uplink radio frame transmission on the Pcell takes placeTTA = (NTA + TAoffset)*T*c before the reception of the first detected path (as defined in TS 38.133) in time on the corresponding DL radio frame. This means that the timing advance must be considered at switching events.

The duration of the switching gap is RRC configured. The network ensures that the switching gap is large enough to cover the switching period (35 , 70μs, and 140 𝜇s according to the UE capability), transient periods and the TA, if needed, in both switch directions.

### 5.2.2 FDD to SDL switch

For the FDD to SDL switch the gNB configures a gap long enough to accommodate timing advance such that no collisions should occur. Figure 5.2.2-1 shows the case with TTA > 0 µs. The figure illustrates the applicable transient periods, switching period (35, 70μs, and 140 𝜇s according to UE capability), and the applicability of ON and OFF power requirements.



Figure 5.2.2-1: FDD to SDL switch with the switching gap on the switched-from carrier.

The UL slot will always end before the DL slot, neglecting any timing errors in case TA = 0 µs. The worst case in terms of switching is that in which TTA = 0 µs, the DL and UL timing are the same (again neglecting the errors that are of the order of 1 µs) and the SDL starts RTD µs before the Pcell DL slot timing. The switching gap with respect to the end of the last FDD DL symbol must therefore be at least

actual switching gap length > Tswitch + MRTD + FDD UL trailing end transient period + SDL leading transient period.

where the MRTD = [CP length/TAE] assuming that the FDD and SDL carriers are colocated.

### 5.2.3 SDL to FDD switch

For the SDL to FDD switch, the switching gap *ends* at end of slot on “switch from” carrier (SDL). The timing advance must also be accounted for; Figure 5.2.3-1 shows the case where the switch is assumed to occur before the start of the time advanced UL. The figure illustrates the applicable transient periods, switching period (35 , 70μs, and 140 𝜇s according to UE capability), and the applicability of ON and OFF power requirements.

<< end change 1 >>

<< begin change 2 >>

## 5.3 Applicability of simultaneous Rx/Tx requirements

The following statement in section 5.2A.2 of TS38.101-1 captures the applicability of simultaneous Rx/Tx requirements when the UE supports the low NR band carrier aggregation via switching: “Concurrent operation between these bands is not applicable to UEs indicating support of low NR band aggregation via switching [*supportedLowBandSwitching-r19*] for this band combination.”

<< end of change 2 >>

<< begin of change 3 >>

## 5.4 CA configurations

Low NR band inter-band CA configurations in which the UE is allowed to indicate support of the configuration via switching [*supportedLowBandSwitching-r19*] are indicated with the corresponding note in the configuration tables in sub-clause 5.5A.3.1 of TS38.101-1.

The following notes to be added in Table 5.5A.3.1-1d of TS38.101-1 next to the band combinations that support low NR band aggregation via switching: “The UEs is allowed to indicate support of low NR band carrier aggregation via switching [*supportedLowBandSwitching-r19*] for this NR CA configuration”.

The following notes to be added in Table 5.5A.3.1-1f of TS38.101-1 next to the band combinations that support low NR band aggregation via switching: “Applicable only for UEs which indicate support of low NR band carrier aggregation via switching [*supportedLowBandSwitching-r19*] for this NR CA configuration”.

<< end of change 3 >>

<< begin of change 4 >>

## 5.5 MSD requirements

The following note to be added in Table 7.3A.6-1 and Table 7.3A.6-1a-1 of TS38.101-1 to indicate that the specified MSD is not applicable to UEs indicating support of low NR band carrier aggregation via switching :.”Not applicable to UEs indicating support of low NR band aggregation via switching [*supportedLowBandSwitching-r19*] for this band combination”

<< end of change 4 >>

<< begin of change 5>>

## 5.6 ΔRIB,c requirements

The following note to be added in Table 7.3A.3.2.1-1 of TS38.101-1 to indicate that the specified ΔRIB,c is not applicable to UEs indicating support of low NR band carrier aggregation via switching : “Not applicable to UEs indicating support of low NR band aggregation only via switching [*supportedLowBandSwitching-r19*] for this band combination”

<< end of change 5>>